



30CTH02
30CTH02S
30CTH02-1
30CTH02FP

Hyperfast Rectifier

Features

- Hyperfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature

$t_{rr} = 30\text{ns max.}$
 $I_{F(AV)} = 30\text{Amp}$
 $V_R = 200\text{V}$

Description/ Applications

International Rectifier's 200V series are the state of the art Hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

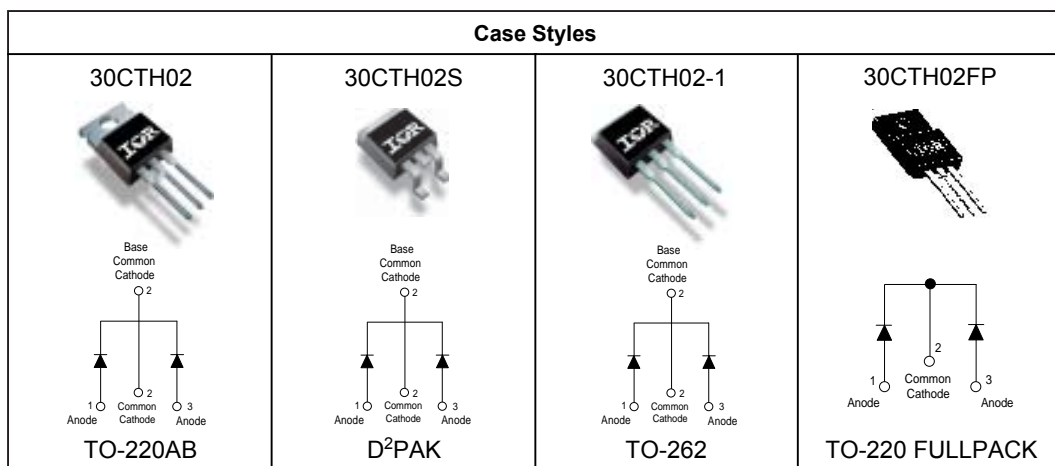
The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Peak Repetitive Reverse Voltage	200	V
$I_{F(AV)}$ Average Rectified Forward Current @ $T_C = 159^\circ\text{C}$ Per Diode @ $T_C = 125^\circ\text{C}$ (FULLPACK) Per Diode	15	A
	Per Device	
I_{FSM} Non Repetitive Peak Surge Current @ $T_J = 25^\circ\text{C}$	200	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	$^\circ\text{C}$



Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V_{BR}, V_r Breakdown Voltage, Blocking Voltage	300	-	-	V	$I_R = 100\mu\text{A}$
V_F Forward Voltage	-	0.92	1.05	V	$I_F = 15\text{A}, T_J = 25^\circ\text{C}$
	-	0.78	0.85	V	$I_F = 15\text{A}, T_J = 125^\circ\text{C}$
I_R Reverse Leakage Current	-	-	10	μA	$V_R = V_R \text{ Rated}$
	-	5	300	μA	$T_J = 125^\circ\text{C}, V_R = V_R \text{ Rated}$
C_T Junction Capacitance	-	57	-	pF	$V_R = 200\text{V}$
L_S Series Inductance	-	8	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_C = 25^\circ\text{C}$ (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t_{rr} Reverse Recovery Time	-	-	35	ns	$I_F = 1\text{A}, di_F/dt = 50\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	-	30		$I_F = 1\text{A}, di_F/dt = 100\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	26	-	$T_J = 25^\circ\text{C}$	$I_F = 15\text{A}$ $di_F/dt = 200\text{A}/\mu\text{s}$ $V_R = 160\text{V}$
	-	40	-	$T_J = 125^\circ\text{C}$	
I_{RRM} Peak Recovery Current	-	2.8	-	A	$T_J = 25^\circ\text{C}$
	-	6.0	-		$T_J = 125^\circ\text{C}$
Q_{rr} Reverse Recovery Charge	-	37	-	nC	$T_J = 25^\circ\text{C}$
	-	120	-		$T_J = 125^\circ\text{C}$

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T_J Max. Junction Temperature Range	-	-	175	$^\circ\text{C}$
T_{Stg} Max. Storage Temperature Range	- 65	-	175	
R_{thJC} ① Thermal Resistance, Junction to Case	Per Diode		1.1	$^\circ\text{C}/\text{W}$
	Fullpack (Per Diode)		3.5	

① Mounting Surface, Flat, Smooth and Greased

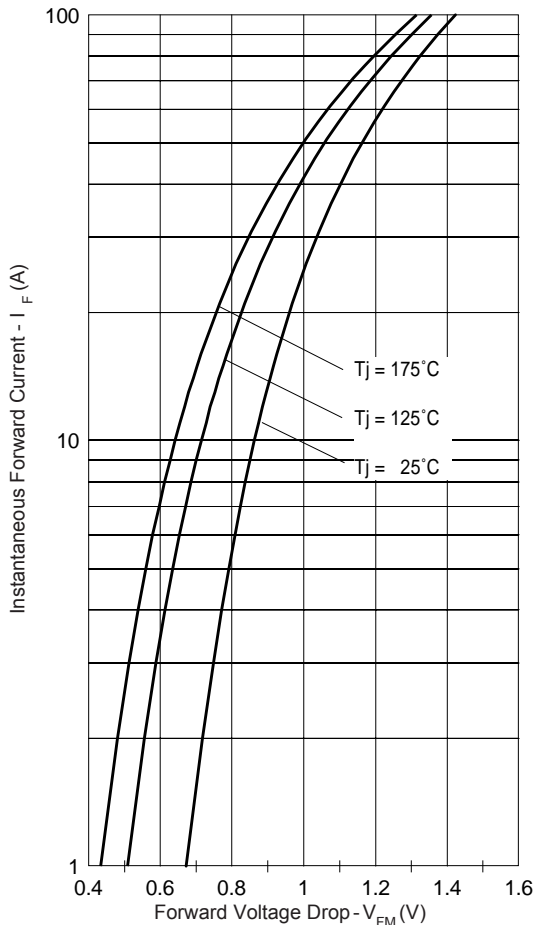


Fig. 1 - Typical Forward Voltage Drop Characteristics

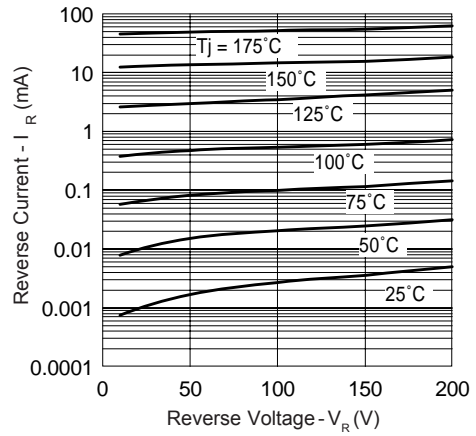


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

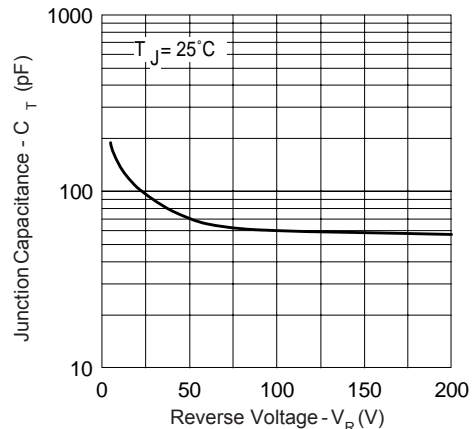


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

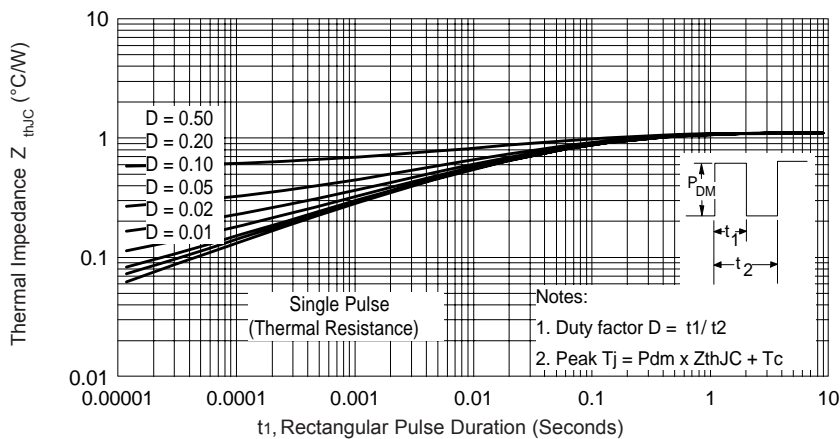


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

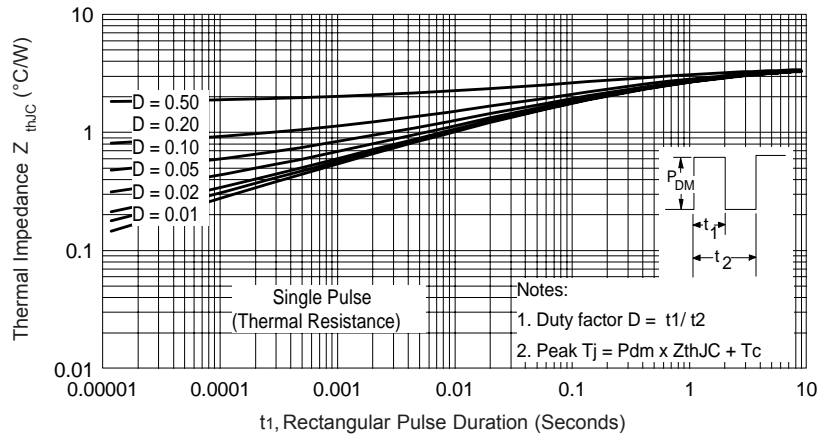


Fig. 5 - Max. Thermal Impedance Z_{thJC} Characteristics (FULLPACK)

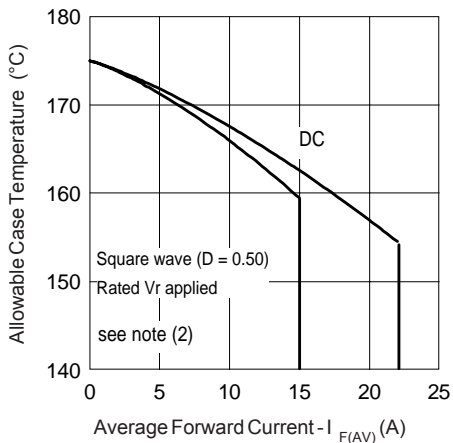


Fig. 6 - Max. Allowable Case Temperature Vs. Average Forward Current

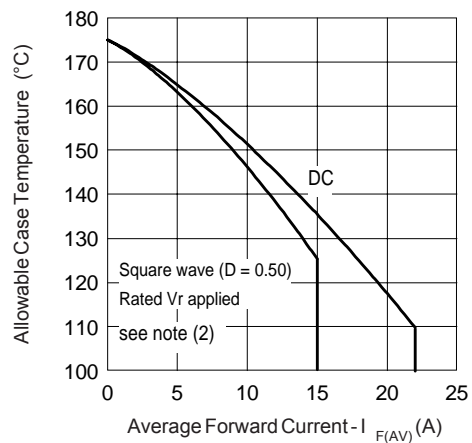


Fig. 7 - Max. Allowable Case Temperature Vs. Average Forward Current (FULLPACK)

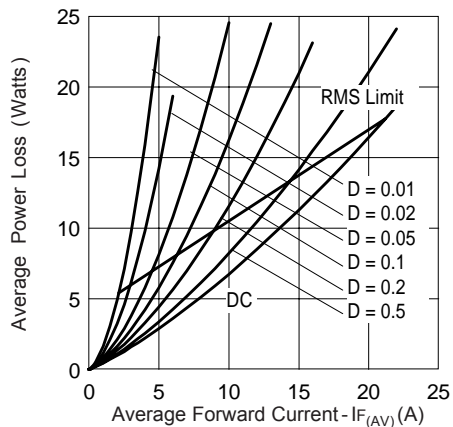


Fig. 8 - Forward Power Loss Characteristics

(2) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$
 (see Fig. 8);
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$;
 $I_R @ V_{R1} = \text{rated } V_R$

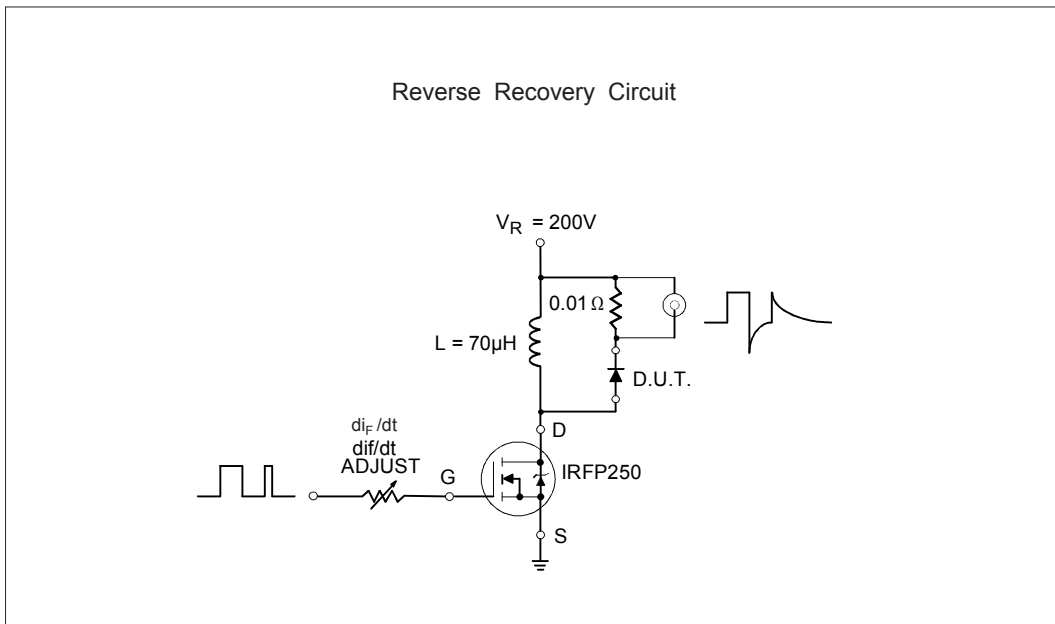
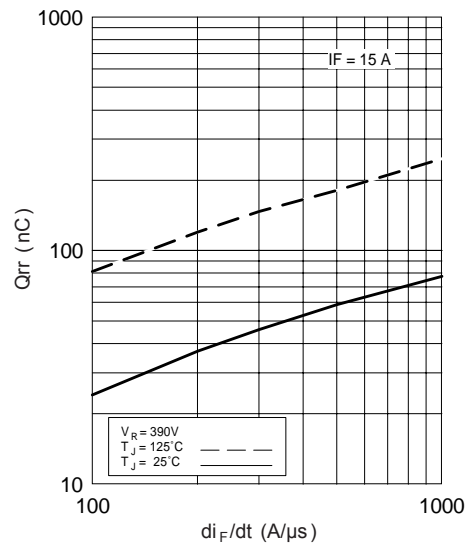
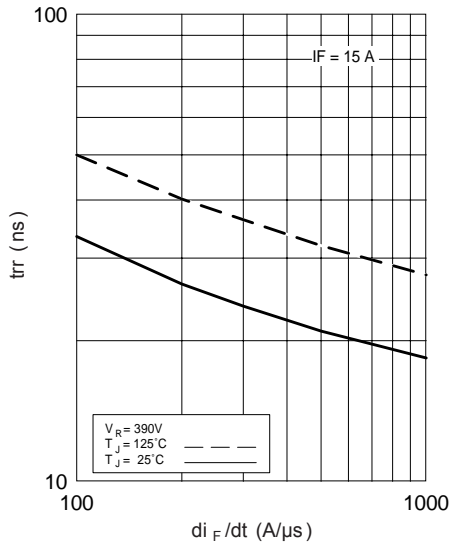


Fig. 11 - Reverse Recovery Parameter Test Circuit

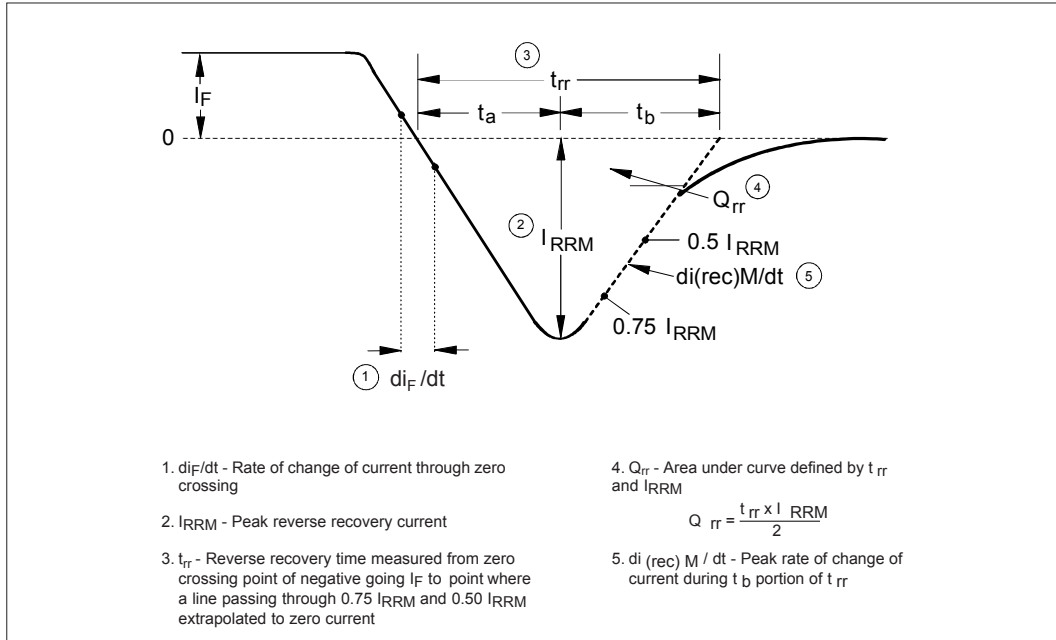
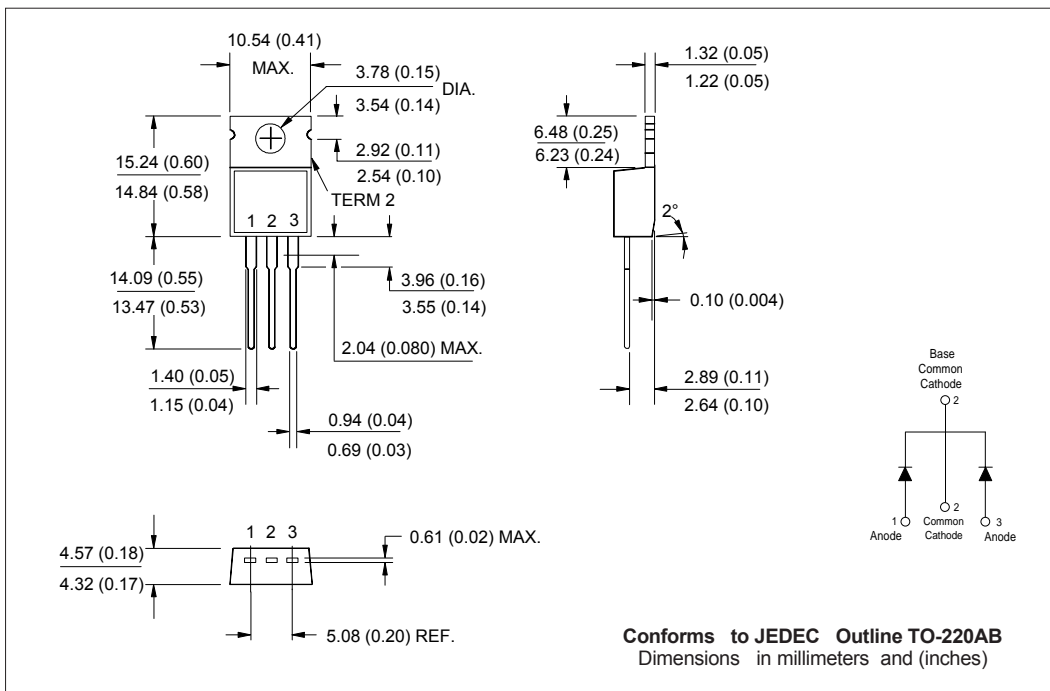
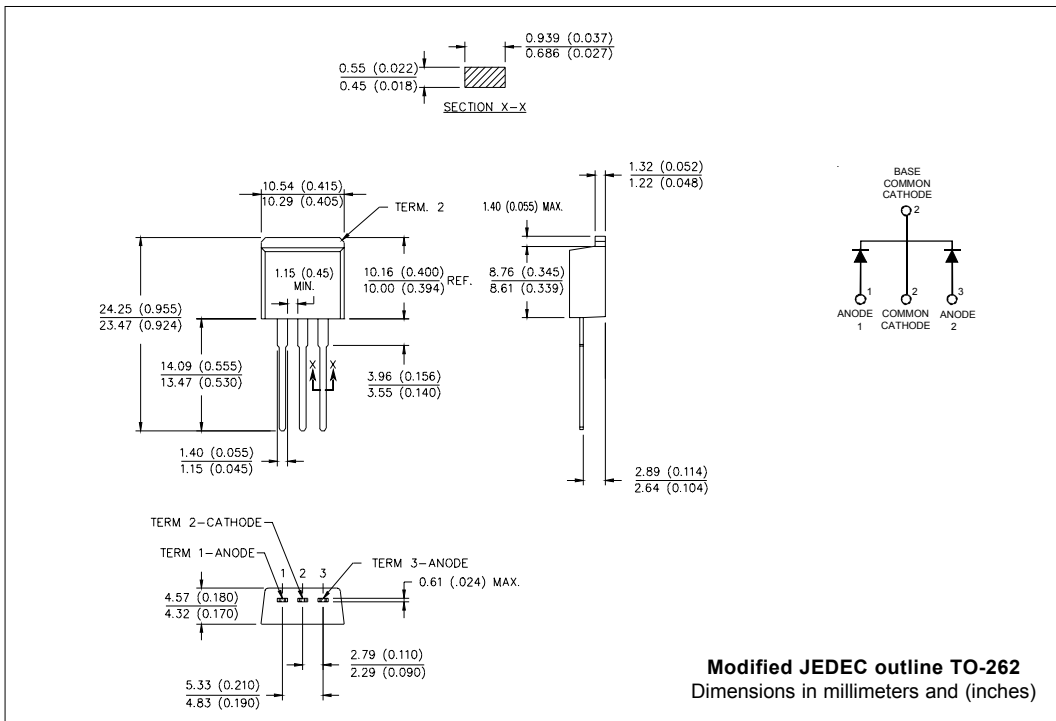
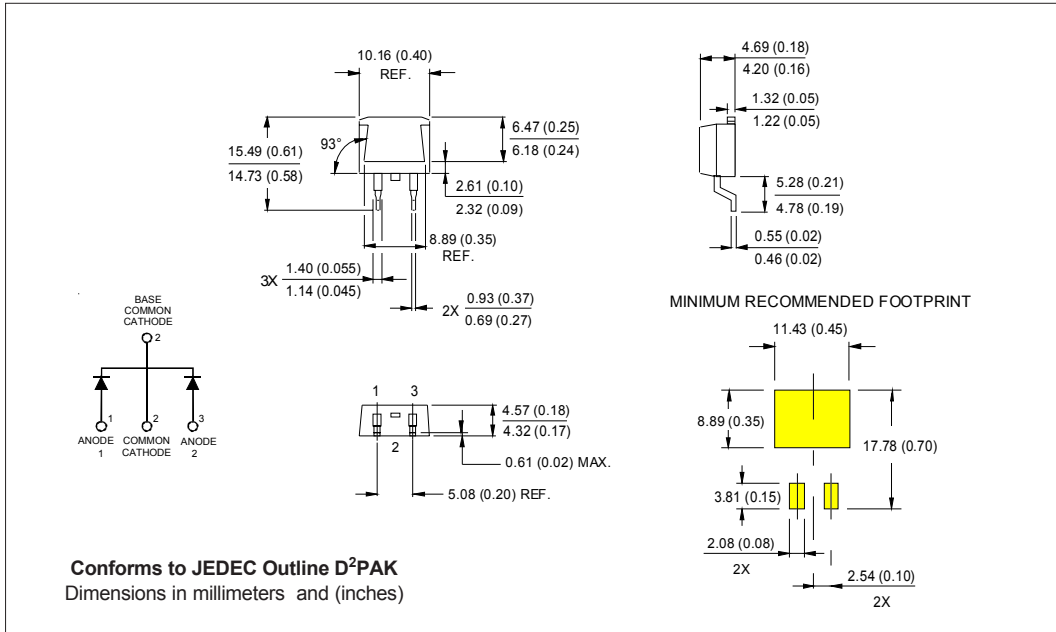


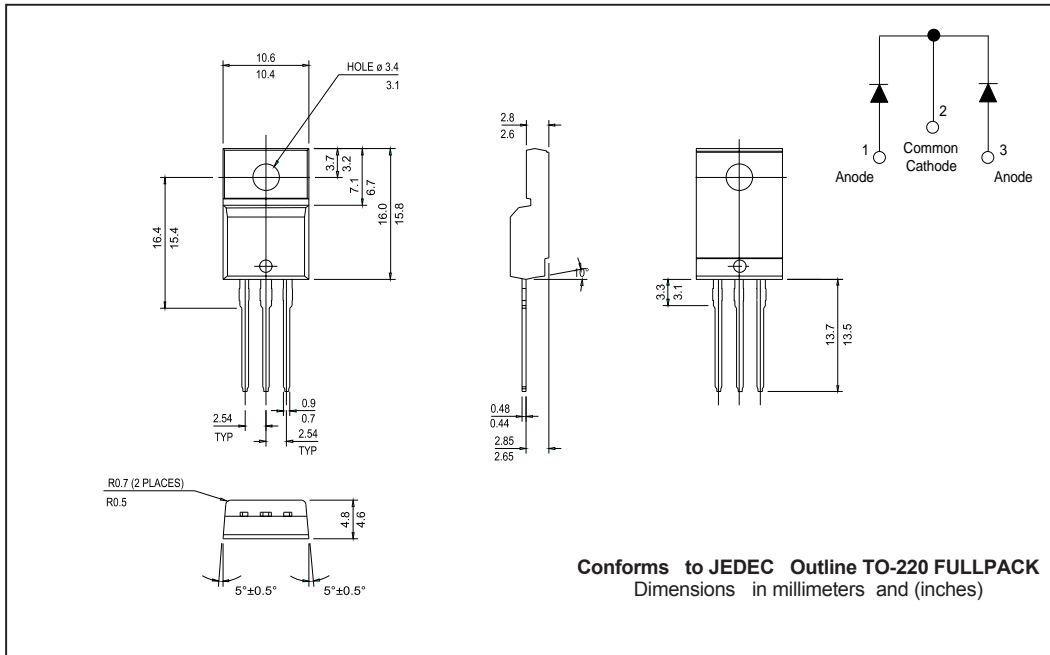
Fig. 13 - Reverse Recovery Waveform and Definitions

Outline Table



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Ordering Information Table

Device Code					
30	C	T	H	02	- 1
①	②	③	④	⑤	⑥
1	- Current Rating (30 = 30A)				
2	- C = Common Cathode				
3	- T = TO-220, D ² Pak				
4	- H = HyperFast Recovery				
5	- Voltage Rating (02 = 200V)				
6	- None = TO-220AC				
	S = D ² Pak				
	"-1" = TO-262 Option				
	FP = TO-220 FULLPACK				

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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